

| L Number | Hits | Search Text | DB | Time stamp |
|----------|---------|--|---|------------------|
| 1 | 159618 | (p adj type) ptype | USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB | 2004/10/03 16:47 |
| 2 | 50560 | group adj (three III iii) | USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB | 2004/10/03 16:48 |
| 3 | 100895 | polycrystalline polycrystal (poly adj (crystal crystalline)) | USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB | 2004/10/03 16:51 |
| 4 | 266306 | nitride gan | USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB | 2004/10/03 16:51 |
| 5 | 980 | ((p adj type) ptype) and (group adj (three III iii)) and (polycrystalline polycrystal (poly adj (crystal crystalline))) and (nitride gan) | USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB | 2004/10/03 16:52 |
| 6 | 68025 | (group adj (three III iii)) gan (gallium adj nitride) | USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB | 2004/10/03 16:53 |
| 7 | 1871 | ((p adj type) ptype) and (polycrystalline polycrystal (poly adj (crystal crystalline))) and ((group adj (three III iii)) gan (gallium adj nitride)) | USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB | 2004/10/03 16:53 |
| 8 | 3259415 | electrode terminal pad | USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB | 2004/10/03 16:54 |
| 9 | 1528 | (electrode terminal pad) and (((p adj type) ptype) and (polycrystalline polycrystal (poly adj (crystal crystalline))) and ((group adj (three III iii)) gan (gallium adj nitride))) | USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB | 2004/10/03 16:54 |
| 10 | 346851 | grain (crystal with grain) | USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB | 2004/10/03 17:35 |
| 11 | 361 | ((electrode terminal pad) and (((p adj type) ptype) and (polycrystalline polycrystal (poly adj (crystal crystalline))) and ((group adj (three III iii)) gan (gallium adj nitride))) and (grain (crystal with grain))) | USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB | 2004/10/03 16:55 |
| 12 | 53 | fiber and (((electrode terminal pad) and (((p adj type) ptype) and (polycrystalline polycrystal (poly adj (crystal crystalline))) and ((group adj (three III iii)) gan (gallium adj nitride))) and (grain (crystal with grain))) | USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB | 2004/10/03 17:34 |
| 13 | 23339 | (polycrystalline polycrystal (poly adj (crystal crystalline))) with (electrode terminal pad) | USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB | 2004/10/03 17:35 |

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|----|-----|--|---|------------------|
| 14 | 334 | ((polycrystalline polycrystal (poly adj (crystal crystalline))) with (electrode terminal pad)) and ((p adj type) ptype) and ((group adj (three III iii)) gan (gallium adj nitride)) | USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB | 2004/10/03 17:35 |
| 15 | 125 | ((polycrystalline polycrystal (poly adj (crystal crystalline))) with (electrode terminal pad)) and ((p adj type) ptype) and ((group adj (three III iii)) gan (gallium adj nitride))) and (grain (crystal with grain)) | USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB | 2004/10/03 17:36 |
| 16 | 0 | ((polycrystalline polycrystal (poly adj (crystal crystalline))) with (electrode terminal pad)) and ((p adj type) ptype) and ((group adj (three III iii)) gan (gallium adj nitride))) and (crystal with grain) | USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB | 2004/10/03 17:36 |
| 17 | 69 | ((polycrystalline polycrystal (poly adj (crystal crystalline))) with (electrode terminal pad)) and ((p adj type) ptype) and ((group adj (three III iii)) gan (gallium adj nitride))) and (crystal with grain) | USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB | 2004/10/03 17:36 |
| 18 | 64 | ((polycrystalline polycrystal (poly adj (crystal crystalline))) with (electrode terminal pad)) and ((p adj type) ptype) and ((group adj (three III iii)) gan (gallium adj nitride))) and (crystal with grain) not (fiber and (((electrode terminal pad) and ((p adj type) ptype) and (polycrystalline polycrystal (poly adj (crystal crystalline))) and ((group adj (three III iii)) gan (gallium adj nitride)))) and (grain (crystal with grain)))) | USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB | 2004/10/03 17:36 |